

SEMITOP® 3

IGBT Module

SK25GD12T4ET

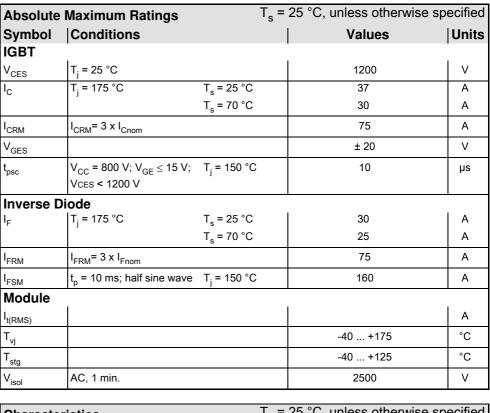
Features

- · One screw mounting module
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor

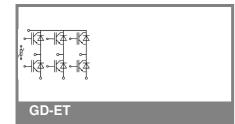
Typical Applications*

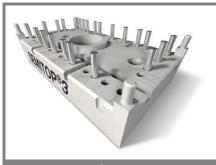
Remarks

• V_{CE.sat} , V_F = chip level value



Characteristics T _s		$T_s =$	= 25 °C, unless otherwise specified				
Symbol	Conditions		min.	typ.	max.	Units	
IGBT							
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_{C} = 0.85 \text{ mA}$		5	5,8	6,5	V	
I _{CES}		T _j = 25 °C			1	mA	
	V _{CE} = 0 V, V _{GE} = 20 V	T _j = 125 °C				mA	
I _{GES}	V _{CE} = 0 V, V _{GE} = 20 V	T _j = 25 °C			120	nA	
		$T_j = 125 ^{\circ}\text{C}$ $T_i = 25 ^{\circ}\text{C}$				nA	
V _{CE0}		T _j = 25 °C		1,1	1,3	V	
		T _j = 150 °C		1	1,2	V	
r _{CE}	V _{GE} = 15 V	T _j = 25°C		30		mΩ	
		T _j = 150°C		50		mΩ	
V _{CE(sat)}	I _{Cnom} = 25 A, V _{GE} = 15 V	T _j = 25°C _{chiplev.}		1,85	2,05	V	
		$T_j = 150^{\circ}C_{chiplev.}$		2,25	2,45	V	
C _{ies}				1,43		nF	
C _{oes}	$V_{CE} = 25, V_{GE} = 0 V$	f = 1 MHz		0,115		nF	
C _{res}				0,085		nF	
Q_G	V _{GE} =-7V+15V			137,5		nC	
t _{d(on)}				22		ns	
t _r	$R_{Gon} = 19 \Omega$	V _{CC} = 600V		19,5		ns	
E _{on}	di/dt = 2825 A/µs	I _C = 25A		2,27		mJ	
t _{d(off)}	$R_{Goff} = 19 \Omega$	T _j = 150 °C		288		ns	
t _f	di/dt = 2825 A/µs	V _{GE} = -7/+15V		77,5		ns	
E _{off}				2,7		mJ	
$R_{th(j-s)}$	per IGBT			1,31		K/W	





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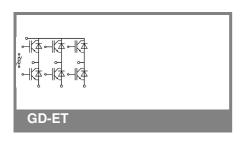
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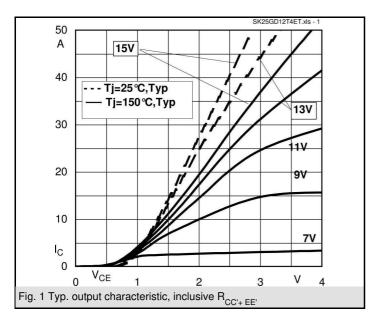
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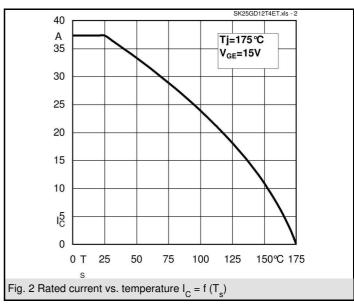
Remarks

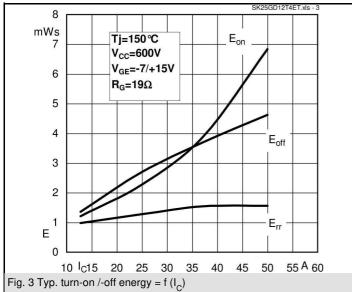
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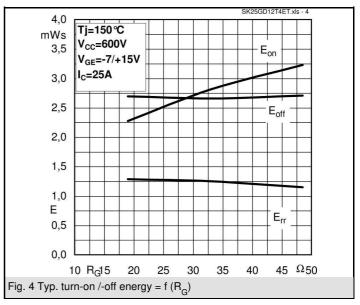


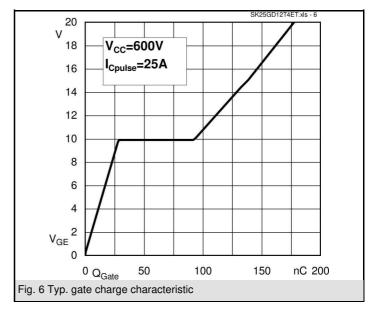
Characteristics									
Symbol	Conditions		min.	typ.	max.	Units			
Inverse D	iode								
$V_F = V_{EC}$	I_{Fnom} = 25 A; V_{GE} = 0 V	$T_j = 25 ^{\circ}C_{\text{chiplev.}}$		2,4	2,62	V			
		T_j = 150 °C _{chiplev} .		2,45	2,8	V			
V _{F0}		T _j = 25 °C		1,3	1,5	V			
		T _j = 150 °C		0,9	1,1	V			
r _F		T _j = 25 °C		44	45	mΩ			
		T _j = 150 °C		62	68	$m\Omega$			
I _{RRM}	I _F = 25 A	T _j = 150 °C		31,5		Α			
Q_{rr}	di/dt = 2825 A/µs			1,15		μC			
E _{rr}	V _{CC} = 600V			1,28		mJ			
$R_{th(j-s)D}$	per diode			1,91		K/W			
M _s	to heat sink		2,25		2,5	Nm			
w				30		g			
Temperature sensor									
R ₁₀₀	T_s =100°C (R_{25} =5kΩ)			493±5%		Ω			

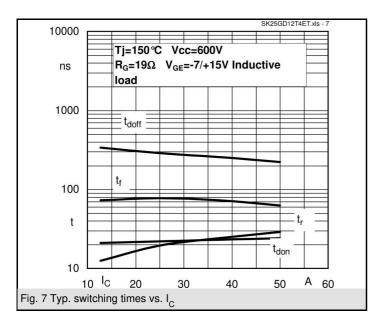


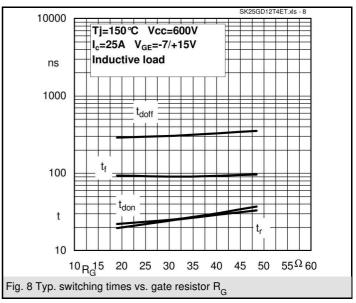


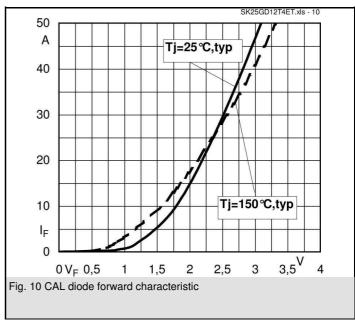


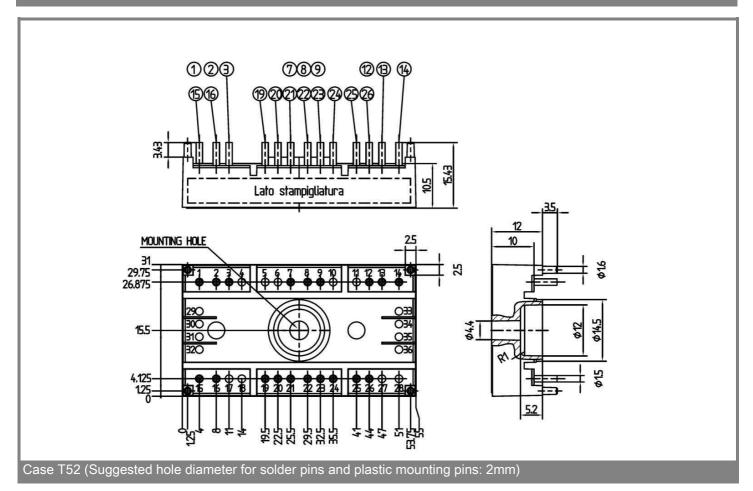


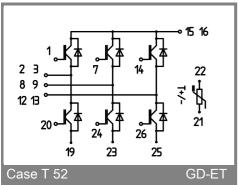












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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